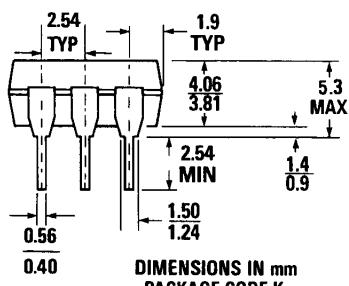
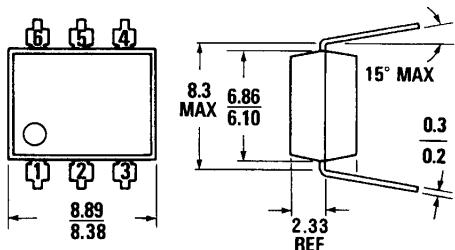




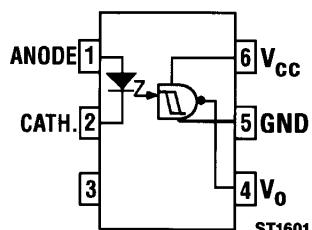
HIGH-SPEED AlGaAs SCHMITT TRIGGER OPTOCOUPLES

H11N1 H11N2 H11N3

PACKAGE DIMENSIONS



ST1603A



Equivalent Circuit

DESCRIPTION

The H11N series has a medium-to-high speed integrated circuit detector optically coupled to a gallium-aluminum-arsenide infrared emitting diode. The output incorporates a Schmitt trigger, which provides hysteresis for noise immunity and pulse shaping. The detector circuit is optimized for simplicity of operation and utilizes an open collector output for maximum application flexibility.

FEATURES & APPLICATIONS

- High data rate, 5 MHz typical (NRZ)
- Free from latch up and oscillation throughout voltage and temperature ranges
- Microprocessor compatible drive
- Logic compatible output sinks 16 mA at 0.5 V maximum
- Guaranteed on/off threshold hysteresis
- High common mode transient immunity 2000 V/ μ s minimum
- Fast switching: $t_s, t_r = 10$ ns typical
- Wide supply voltage capability, compatible with all popular logic systems
- Underwriters Laboratory (UL) recognized — file #E90700
- Logic to logic isolator
- Programmable current level sensor
- Line receiver—eliminates noise and transient problems
- Logic level shifter—couples TTL to CMOS
- A.C. to TTL conversion—square wave shaping
- Isolated power MOS driver for power supplies
- Interfaces computers with peripherals

ABSOLUTE MAXIMUM RATINGS

TOTAL PACKAGE

Storage temperature	-55°C to 125°C
Operating temperature	-25°C to 85°C
Lead solder temperature	260°C for 10 sec

INPUT DIODE

Power dissipation (25°C ambient)	50 mW
Derate linearly (above 70°C)	1.67 mW/°C
Continuous forward current	30 mA
Peak forward current (300 μ s pulse, 2% duty cycle)	50 mA
Reverse voltage	6 V

DETECTOR

Power dissipation (at 25°C ambient)	150 mW
Derate linearly (above 25°C ambient)	5 mW/°C
V_{45} allowed range	0 to 16 V
V_{65} allowed range	0 to 16 V
I_o , output current	50 mA



HIGH-SPEED AlGaAs SCHMITT TRIGGER OPTOCOUPLES

ELECTRICAL CHARACTERISTICS ($T_A = 0-70^\circ\text{C}$ Unless Otherwise Specified) Note 1

INDIVIDUAL COMPONENT CHARACTERISTICS

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
INPUT DIODE						
Forward voltage	V_F		1.6	2.0	V	$I_F=10 \text{ mA}$
	V_F	0.75	1.45		V	$I_F=0.3 \text{ mA}$
Reverse current	I_R			10	μA	$V_R=5 \text{ V}, T_A=25^\circ\text{C}$
	I_R			100	μA	$V_R=5 \text{ V}, T_A=100^\circ\text{C}$
Capacitance	C_J			100	pF	$V=0 \text{ V}, f=1 \text{ MHz}$
OUTPUT DETECTOR						
Operating voltage range	V_{CC}	4		15	V	
Supply current	$I_{S(on)}$		5.5	10	mA	$I_F=0, V_{CC}=5 \text{ V}$
Output current, high	I_{OH}			100	μA	$I_F=0.3 \text{ mA}, V_{CC}=V_o=15 \text{ V}$

TRANSFER CHARACTERISTICS ($T_A = 0-70^\circ\text{C}$) Note 1

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
Supply current	$I_{S(on)}$		5	10	mA	$I_F=10 \text{ mA}, V_{CC}=5 \text{ V}$
Output voltage, low	V_{OL}		0.3	0.5	V	$R_L=270 \Omega, V_{CC}=5 \text{ V}, I_F=I_{S(on)} \text{ max.}$
Turn-on threshold current (H11N1)	$I_{F(on)}$	0.8		3.2	mA	$R_L=270 \Omega, V_{CC}=5 \text{ V}$
(H11N2)	$I_{F(on)}$	2.3		5.0	mA	$R_L=270 \Omega, V_{CC}=5 \text{ V}$
(H11N3)	$I_{F(on)}$	4.1		10.0	mA	$R_L=270 \Omega, V_{CC}=5 \text{ V}$
Turn-off threshold current	$I_{F(off)}$	0.3	1.5		mA	$R_L=270 \Omega, V_{CC}=5 \text{ V}$
Hysteresis ratio	$I_{F(off)}/I_{F(on)}$	0.65	0.8	0.95		$R_L=270 \Omega, V_{CC}=5 \text{ V}$



HIGH-SPEED AlGaAs SCHMITT TRIGGER OPTOCOUPLES

DYNAMIC CHARACTERISTICS ($T_A = 0\text{-}70^\circ\text{C}$) Note 1						
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
SWITCHING SPEED (Figures 7&8)						
Propagation delay, high to low	t_{PHL}	150	330	ns	$C=120\text{ pF}$, $I_E=1\text{ }\mu\text{s}$, R_E : Note 4	
Rise time	t_r	10		ns	$C=120\text{ pF}$, $I_E=1\text{ }\mu\text{s}$, R_E : Note 4	
Propagation delay, low to high	t_{PLH}	150	330	ns	$C=120\text{ pF}$, $I_E=1\text{ }\mu\text{s}$, R_E : Note 4	
Fall time	t_f	15		ns	$C=120\text{ pF}$, $I_E=1\text{ }\mu\text{s}$, R_E : Note 4	
Data rate		5		MHz		Note 3
OVERDRIVE SWITCHING (FIGURES 7&8), NOTE 2						
Turn-off time	t_{off}	0.2	0.5	μs	$C=0$, $R_L=270\text{ }\Omega$, $I_E(\text{MAX})$ H11N1: 5 mA H11N2: 10 mA H11N3: 20 mA	
TRANSIENT IMMUNITY (FIGURE 9)						
Common mode transient immunity	CM_H	± 2000	± 10000	$V/\mu\text{s}$	$V_{pk}=50\text{ V}$, $V_{cc}=5\text{ V}$, $R_L=270\text{ }\Omega$, $I_E=0$	
Common mode transient immunity	CM_L	± 2000	± 10000	$V/\mu\text{s}$	$V_{pk}=50\text{ V}$, $V_{cc}=5\text{ V}$, $R_L=270\text{ }\Omega$, $I_E=0$	

ISOLATION CHARACTERISTICS						
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
Surge isolation voltage	V_{ISO}	7500			V_{PEAK}	1 Minute
Surge isolation voltage	V_{ISO}	5300			V_{RMS}	1 Minute

Notes
1. All measurements are with 100nF bypass capacitor from pin 6 to pin 5.
2. Steady overdrive increases t_r . Use of a large R_E and a small C as in figure 7 is preferred over overdrive current.
3. Maximum data rate will vary depending on the bias conditions and is usually highest when R_E and C are matched to I_{IOH} and V_{cc} is between 5 and 15V. With this optimized bias, most units will operate at over 10 MHz, NRZ.
4. H11N1: $R_E = 910\Omega$, H11N2: $R_E = 560\Omega$, H11N3: $R_E = 240\Omega$.



OPTOISOLATOR SPECIFICATIONS

TYPICAL CHARACTERISTICS

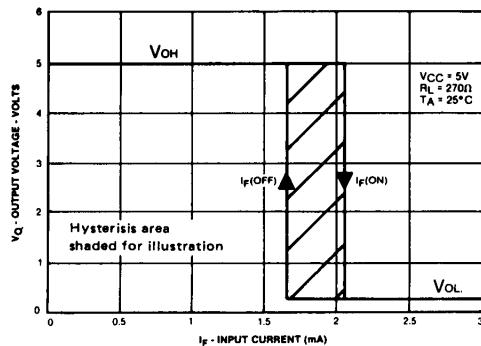


Figure 1. Transfer characteristics ST2022

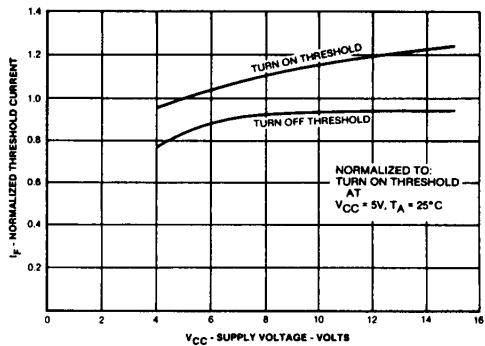


Figure 2. Threshold current vs. supply voltage ST2023

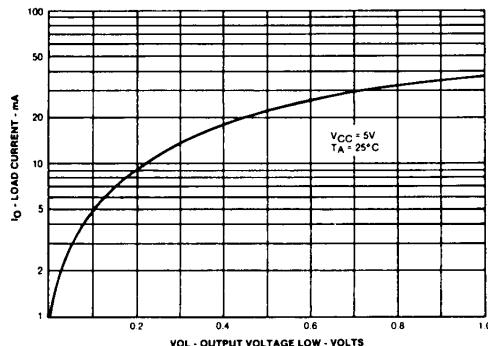


Figure 3. ON voltage vs. current ST2024

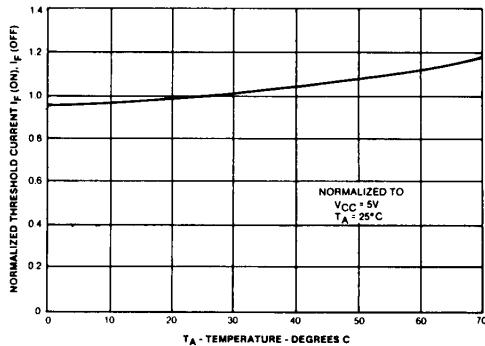


Figure 4. Threshold current vs. temperature ST2025

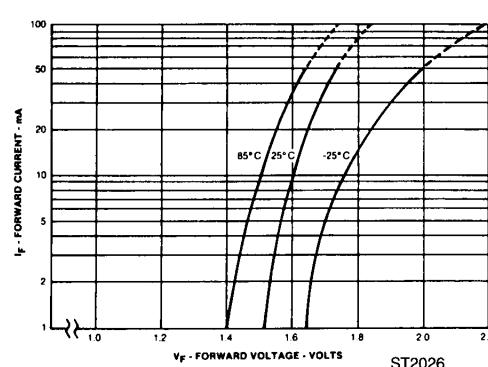


Figure 5. Forward voltage vs. forward current ST2026

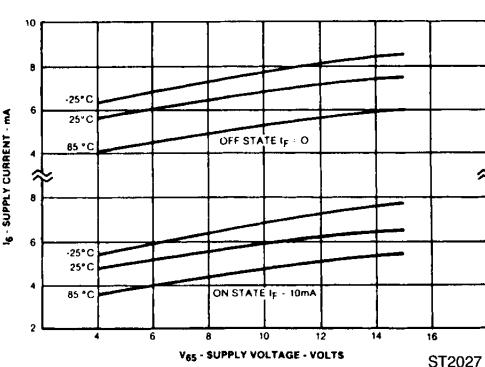
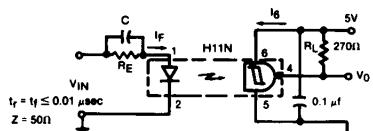


Figure 6. Supply current vs. supply voltage ST2027

OPTOISOLATOR SPECIFICATIONS

TYPICAL CHARACTERISTICS



ST2028

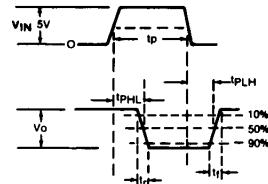
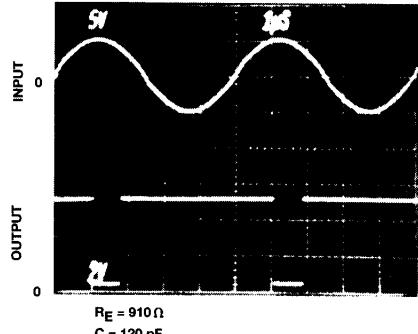


Figure 7. Switching test circuit



ST2029

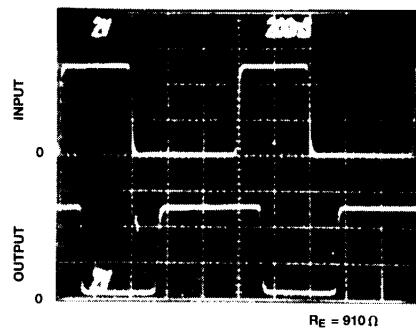


Figure 8. Switching test waveforms

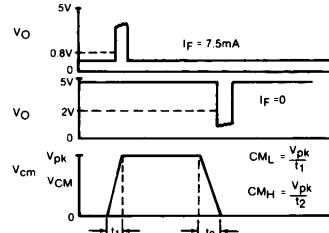
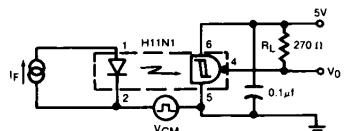


Figure 9. Common-mode transient immunity, test circuit and voltage waveforms

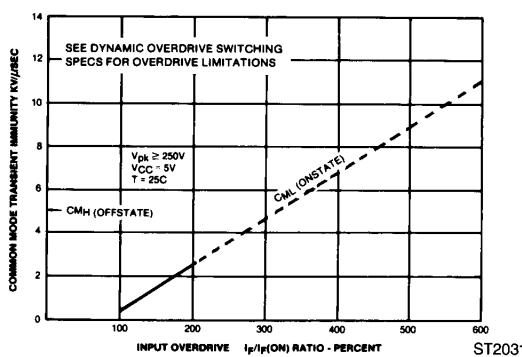


Figure 10. CM_L and CM_H input current

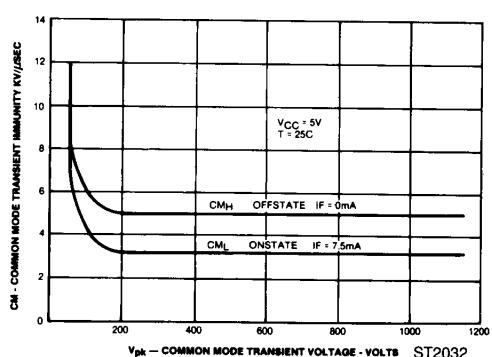


Figure 11. CM_L and CM_H vs. common-mode transient voltage